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# Radio Frequency Systems

**“Mini-CAS” course on Mechanical and Materials Engineering for Accelerators, April 9, 2021**



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# Outlook Presentation

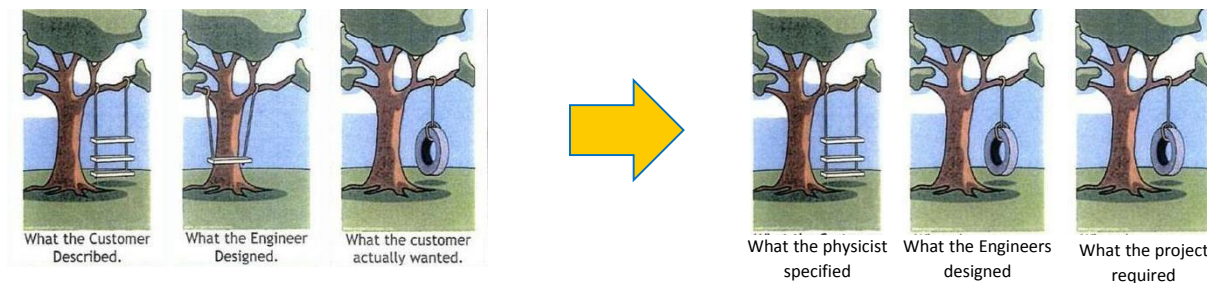
- Introduction
- Overview function RF systems and their generic topology
- Transmissions Lines
- Itroduction to RF (accelerating) structures
- Excursion in the UHP machining for RF

# From where I am calling you for the CAS

[www.psi.ch](http://www.psi.ch)



- We will concentrate on classical normal conducting RF systems. We will not cover the particular engineering aspects of Superconducting RF systems
- We will illustrate via few examples, *most related to applications and developments at PSI*, the mechanical engineering aspects relevant for the design and production of RF accelerating structures and RF components
- Beside some key formula, basic concepts and key parameters we will try to minimize the mathematics and concentrate on the interface between RF requirements and mechanical engineering/production





# RF & Engineering: some important aspects to keep in mind

## RF systems are always (**very**) expensive

- ⇒ It is not uncommon if representing a large fraction of the total accelerator/project budget

## RF handles high power & voltages

- ⇒ Complex system with high potential of failures (can strongly influence the accelerator reliability)
- ⇒ Requires careful design and engineering
- ⇒ Engineers must always consider maintainability during the design phase

## Some other constraints

- ⇒ Choice of the RF frequency is often restricted to already existing (commercial) RF sources & components. Developments may be unavoidable but deviations from standards imply substantial additional costs and time
- ⇒ Space in the existing or planned (costs) facilities
- ⇒ Significant development and procurement time



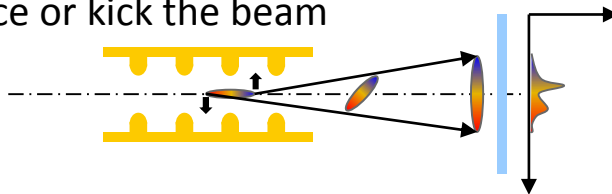
Overdesign, reliability and maintenance not always compatible...\*

# Function of RF: few quick examples

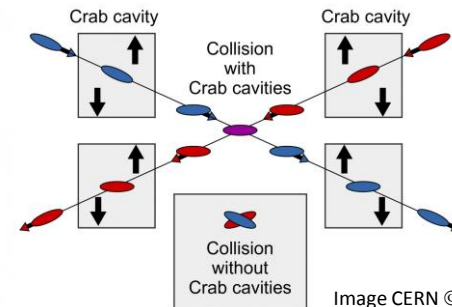
1. Create a large voltage for the acceleration of charged particles or to compensate the Synchrotron radiation losses in Storage Rings



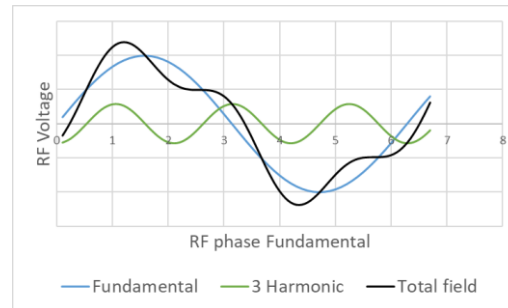
2. Deflect particle bunches transversally to diagnose the longitudinal phase space or kick the beam



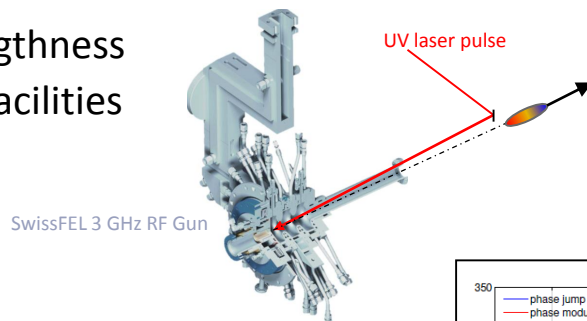
3. Deflect colliding bunches to increase the collision luminosity  
(Crab cavities: <https://home.cern/news/news/accelerators/crab-cavities-colliding-protons-head>)



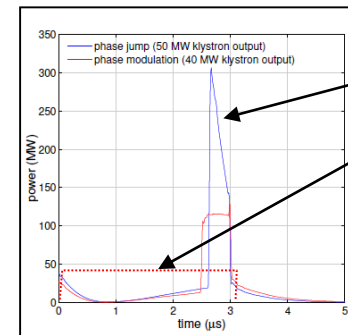
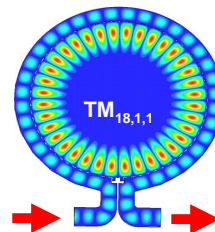
4. RF gymnastic for example for elongating particle bunches in storage rings with the help of Harmonic systems



5. Photo-Cathode RF-Gun as high brightness electron sources typically for FEL facilities



6. Compress RF pulses to achieve higher Peak power from existing pulsed RF surces





## IEEE Standard 521-2002

### Standard Radar Frequency Letter-Band Nomenclature

Band	Frequency Range	Wavelength
HF	3 MHz to 30 MHz	10 meter to 1 meter
VHF	30 MHz - 300 MHz	1,000cm to 100cm
UHF	300 MHz - 1 GHz	100cm to 30 cm
L band	1 GHz to 2 GHz	30cm to 15cm
S band	2 GHz - 4 GHz	15cm to 7.5cm
C band	4 GHz - 8 GHz	7.5cm to 3.8cm
X band	8 GHz - 12 GHz	3.8cm to 2.5cm
K <sub>u</sub> band	12 GHz - 18 GHz	2.5 to 1.7 cm
K band	18 GHz - 27 GHz	1.7 to 1.1 cm
K <sub>a</sub> band	27 GHz - 40 GHz	1.1 to 0.75 cm
V band	40 GHz - 75 GHz	0.75 to 0.40 cm
W band	75 GHz - 100 GHz	0.40 to 0.27 cm
mm	110 to 300 GHz	0.27 to 0.10 cm

Typical for  
Electron  
accelerators

Typical for  
Proton & Ion  
accelerators

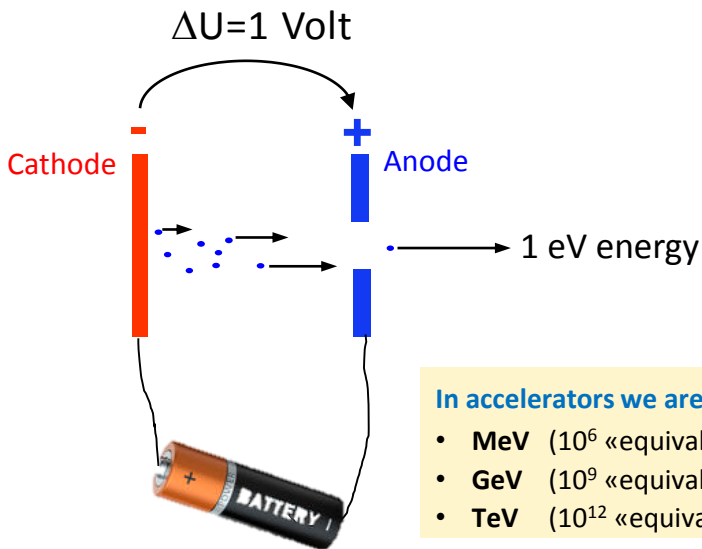
Example S-Band in Linacs: US frequency **2.856 GHz** - European frequency **2.998 GHz** (different standards)

# Small parenthesis: definition of eV (used in next slides)

Just a practical units for particle energy

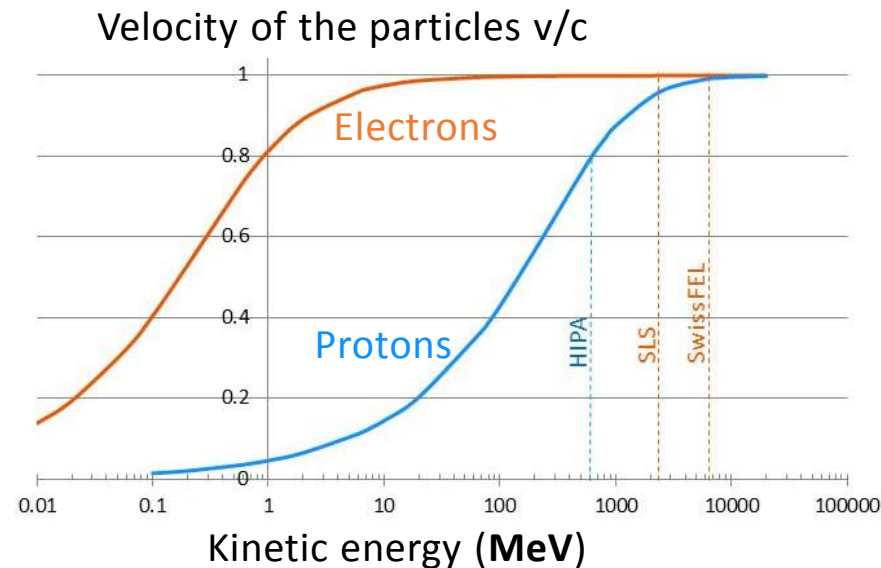
$$1 \text{ eV} = 1.602 \times 10^{-19} \text{ J}$$

Refer to the electron/proton charge



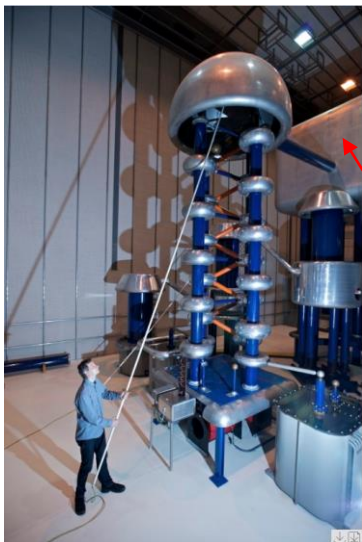
In accelerators we are typically dealing with:

- **MeV** ( $10^6$  «equivalent volts»)
- **GeV** ( $10^9$  «equivalent volts»)
- **TeV** ( $10^{12}$  «equivalent volts»)



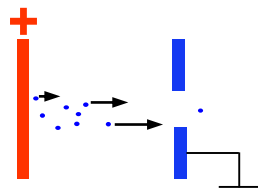
$$E_k = E - E_0 = (\gamma - 1)m_0c^2 \rightarrow \frac{v}{c} = \sqrt{1 - \frac{1}{\gamma^2}} = \sqrt{1 - \left( \frac{1}{1 + \frac{E_{cin}}{m_0c^2}} \right)^2}$$

- RF allow reaching higher energy gains than DC Configurations with a more compact topology
- The fields are confined inside the RF structure => The RF structure is grounded

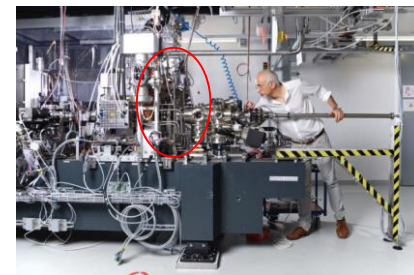


**1 MV** Cockcroft-Walton:  
the first stage in the High  
Intensity Proton  
Accelerator (HIPA) facility

HV Housing of  
the ~1 MeV  
Proton source



**7.1 MeV** SwissFEL RF-Gun  
Peak gradient 100 MV/m

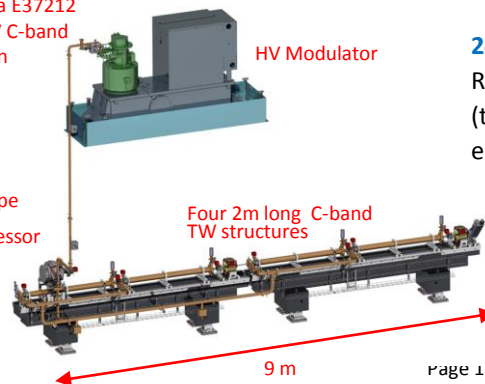


Toshiba E37212  
50 MW C-band  
klystron

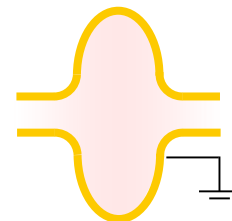
HV Modulator

BOC type  
pulse  
compressor

Four 2m long C-band  
TW structures

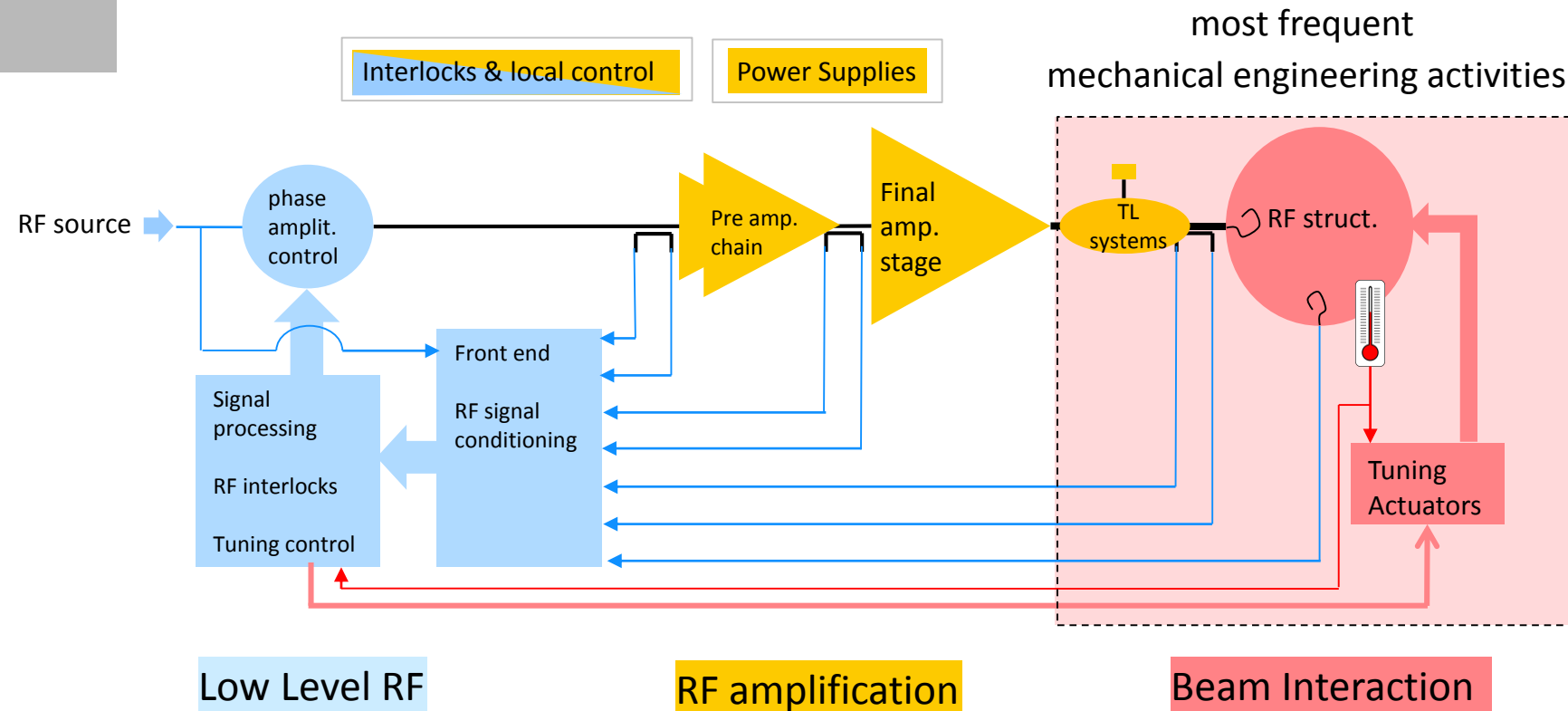


**240 MeV energy gain** SwissFEL C-Band  
RF-Module Gradient ~30 MV/m  
(the cavities would allow >56 MV/m if  
enough RF power)

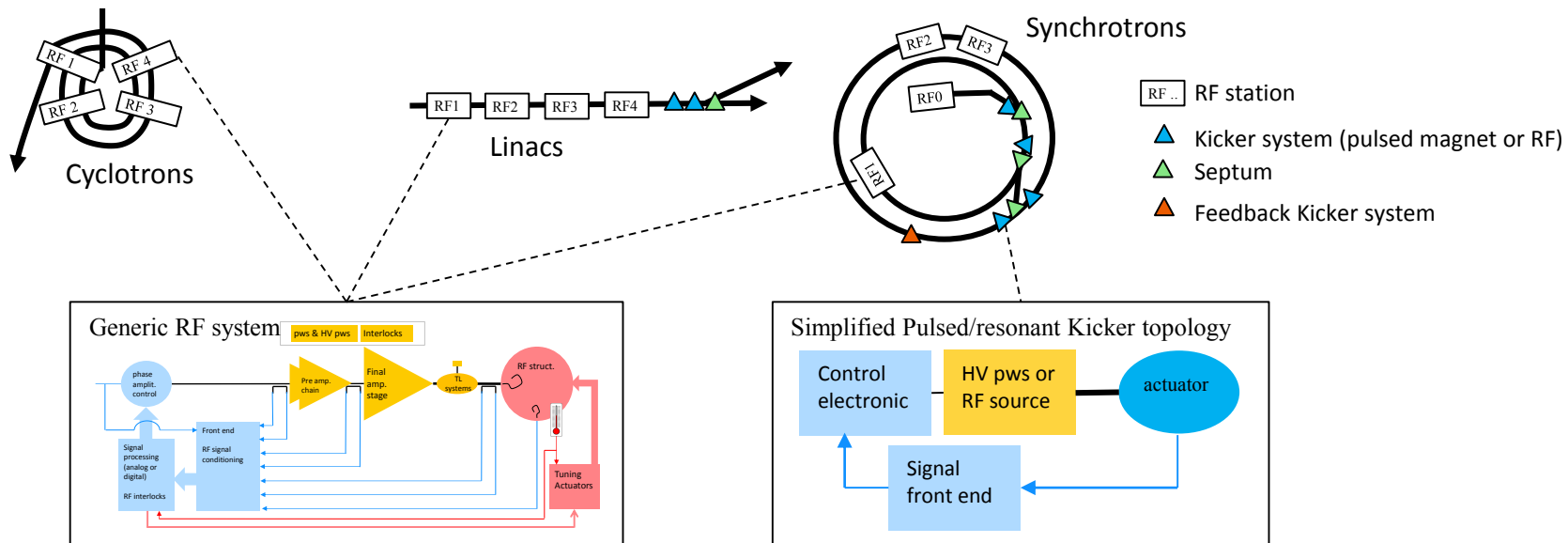


# General Topology of an RF System

*cw (continuous-wave) or pulsed)*



From the operation point of view each RF station or extraction element is seen and handled as a **black-box system** delivering the required accelerating voltage/amplitude and phase stability.



From the RF point of view one RF station is a **complex combination of sub-systems** that must carefully be “matched” to guarantee a stable and reliable user operation.

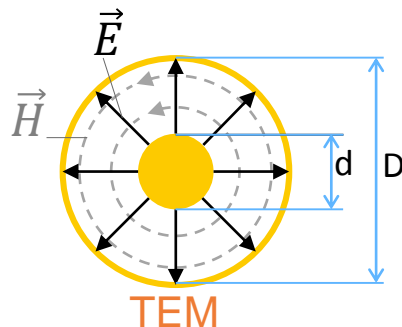
# Transmission line: coaxial

- Very common transmission line for low power signals
- Impedance of the line

$$Z \approx \frac{60}{\sqrt{\epsilon_r}} \ln \left( \frac{D}{d} \right) \quad [\Omega]$$

$$Z = 50 \, \Omega \Leftrightarrow D/d=2.302$$

$$Z = 75 \, \Omega \Leftrightarrow D/d=3.493$$



See for example:

<https://www.zseries.in/electronics%20lab/cables/coaxial/#.YGrbtu2xVjE>

- No cutoff frequency for **TEM** mode, but for high frequencies and large dimensions other modes (with cut off are present) => limitation for high power @ high frequency
- For high power **rigid** coaxial lines => difficulty: cooling of central conductor

Some Rigid coaxial standards (50  $\Omega$ )

Standard designation Size in inch	D (mm)	d (mm)
1-5/8"	38.79	16.87
3-1/8"	76.89	33.40
4-1/16"	99.95	43.46
6-1/8"	151.92	66.04
9-3/16"	228.60	99.31

Commercial rigid coax. from Spinner  
<https://www.spinner-group.com>



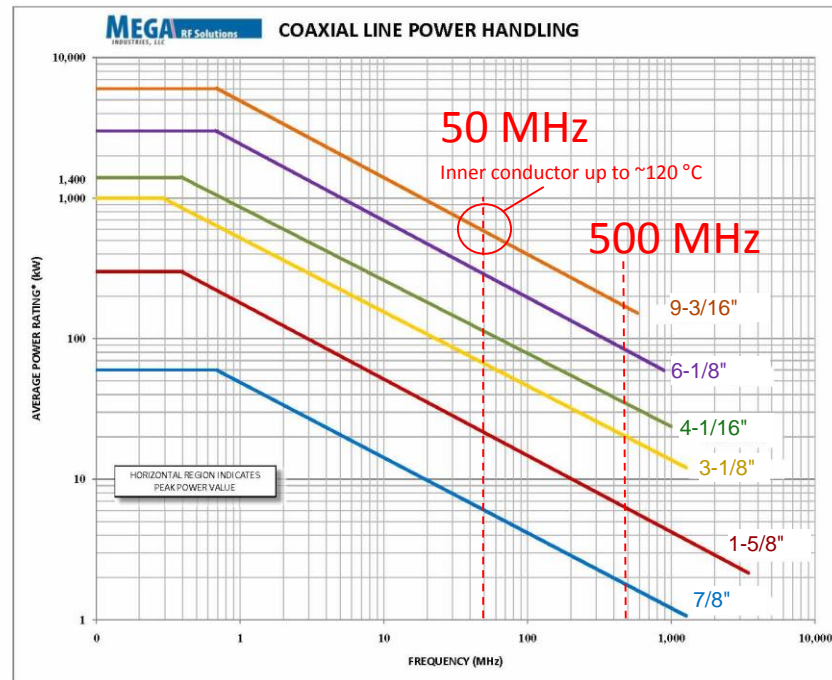
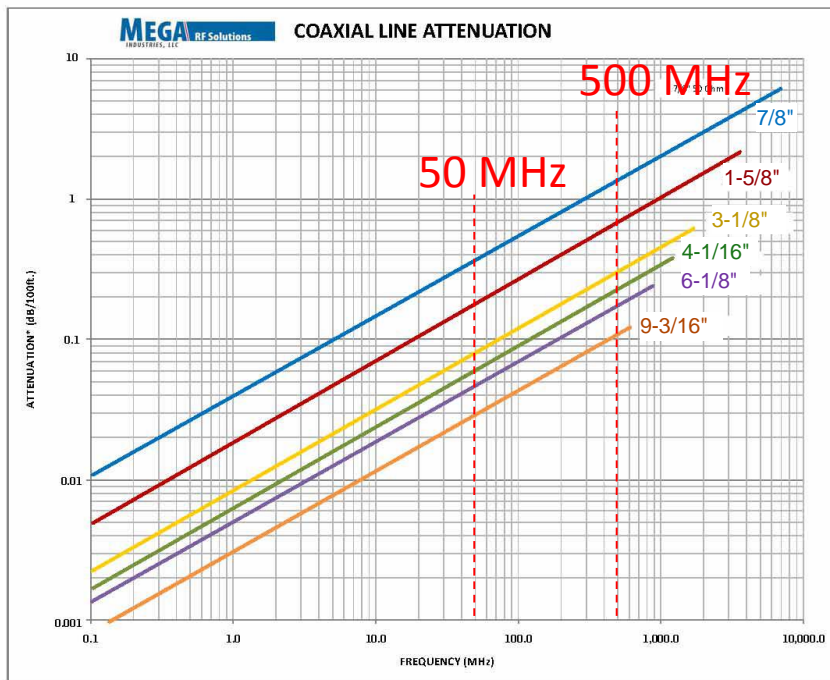
More on coax.see for example: <https://cds.cern.ch/record/865921/files/p210.pdf>



$$\text{Peak Voltage } V_p = E_d \frac{d}{2} \ln \left( \frac{D}{d} \right) \quad [\Omega]$$

$E_d$ : insulator breakdown gradient (V/m)

tendency: the higher the frequency, the lower the breakdown strength



# Transmission line: Coax

## Important information to keep

Rigid coax lines are necessary to handle high power

No Cutoff frequency for the TEM Mode. Signals can propagate from DC to high frequencies

Many commercial supplier delivers Rigid coax components, Sizes are standardized but manufacturer have sometime special dimensions.

For accelerator applications 50  $\Omega$  lines are commonly used  $\Rightarrow$  ratio outer/inner diameter

The power losses in the coax lines increases with frequency but decreases if increasing the size of the line. The optimization stops when TE Modes starts propagating or the losses are too important (increasing with frequency).

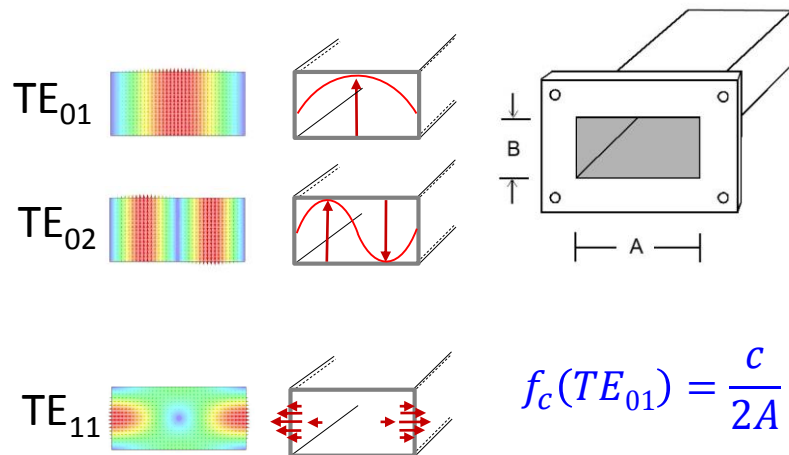
For RF frequencies higher than  $\sim 500$  MHz rigid coax are not suited for high power ( $>100$  kW)

# Transmission line: Waveguides

## Rectangular WG basics

For High Power, high frequency and narrow-band applications rectangular Waveguide are commonly used to transport the RF power from the source to the RF structure.

- A WG allow the propagation of different modes with different cutoff frequencies ( $f_c$ ).
- The size is selected depending on the chosen RF frequency to keep one single mode propagating ( $TE_{01}$ )



$$f_c(TE_{01}) = \frac{c}{2A}$$

With c being the speed of light

WR Designation	Standard Freq Range (GHz)	Inside dimension		Cutoff TE <sub>10</sub> (GHz)	Cutoff Next mode (GHz)
		A (mm)	B (mm)		
WR340	2.20 - 3.30	86.360	43.180	1.74	3.47
WR284	2.60 - 3.95	72.136	34.036	2.08	4.16
WR229	3.30 - 4.90	58.166	29.210	2.58	5.15
WR187	3.95 - 5.85	47.549	22.149	3.15	6.30
WR159	4.90 - 7.05	40.386	20.193	3.71	7.42
WR137	5.85 - 8.20	34.849	15.799	4.30	8.60
WR112	7.05 - 10.00	28.499	12.624	5.26	10.52
WR90	8.2 - 12.4	22.860	10.160	6.56	13.11
WR75	10.0 - 15.0	19.050	9.525	7.87	15.74
WR62	12.4 - 18.0	15.799	7.899	9.49	18.98

S-Band

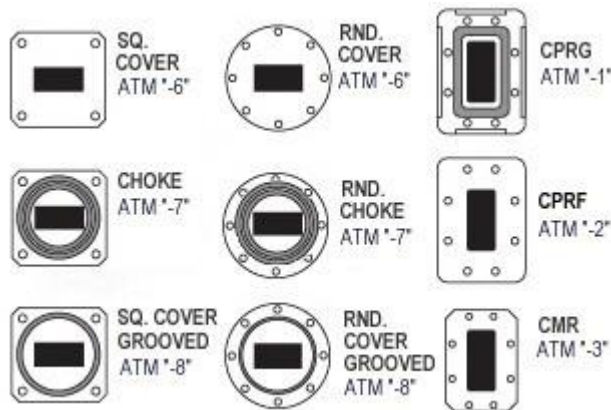
C-Band

X-Band

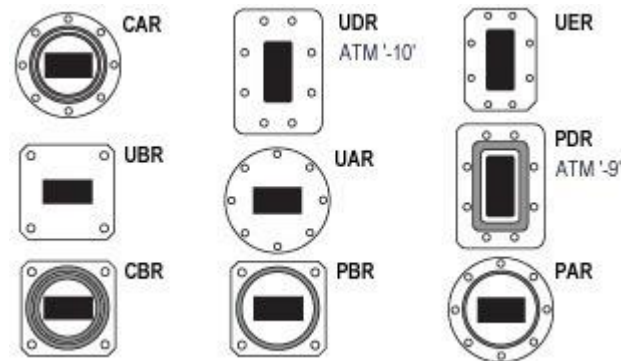
Standard WG (Industrial references are easily available in Internet)

# Transmission line: Waveguides

## WG Flanges



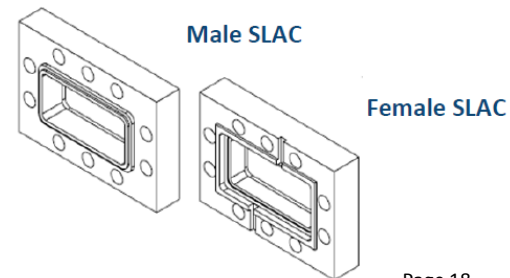
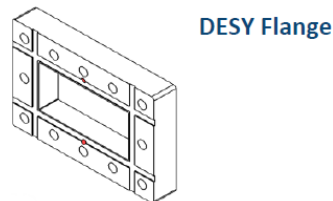
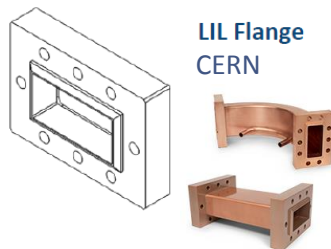
North American EIA Standard Flanges



European IEC Standard Flanges

Examples of WR284 Flanges developed by acc. institutes

- **High power**
- **Vacuum compatible**
- **Excellent electrical contacts**



# Transmission line: Waveguides

## Important information to keep

Waveguide are standardized industrial products, the operating frequency determines the WG dimensions

In the specified frequency band only the mode with the lowest cutoff frequency (TE<sub>01</sub>) propagates => well defined polarization of the electric field => no mode conversion/superposition

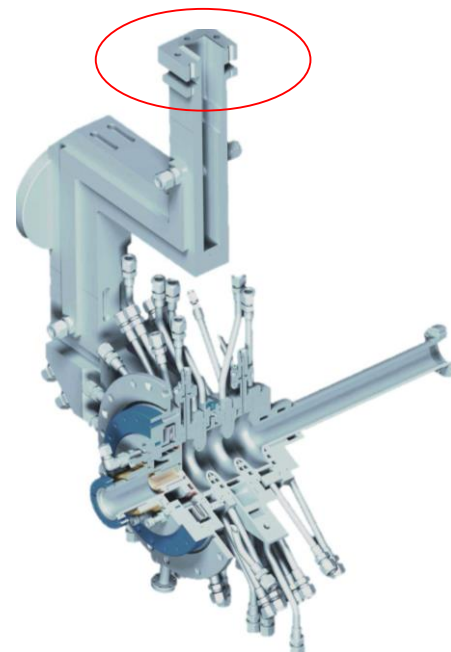
The RF and mechanical design of the interface with the RF structure must be matched to the required WG standard

Waveguide can be operated in Vacuum, on air or with insulating gases as Sulfur hexafluoride (SF<sub>6</sub>) => Flange quality is essential

High power operation in vacuum requires very clean surfaces. An advantage if compatible with 120-150 °C bake-out

The best flanges were designed by acc. Institutes and commercialized  
=> good electrical contact and vacuum compatibility

Interface to WR284  
with LIL flange



SwissFEL RF-Gun

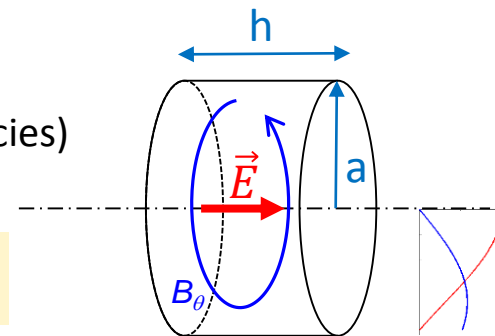
# Basic RF accelerating structures

## Pill box cavity

Nice example with analytic solutions => closed cylindrical Waveguide  
In a cylindrical WG TE and TM modes can propagate ( $\neq$  cut off frequencies)

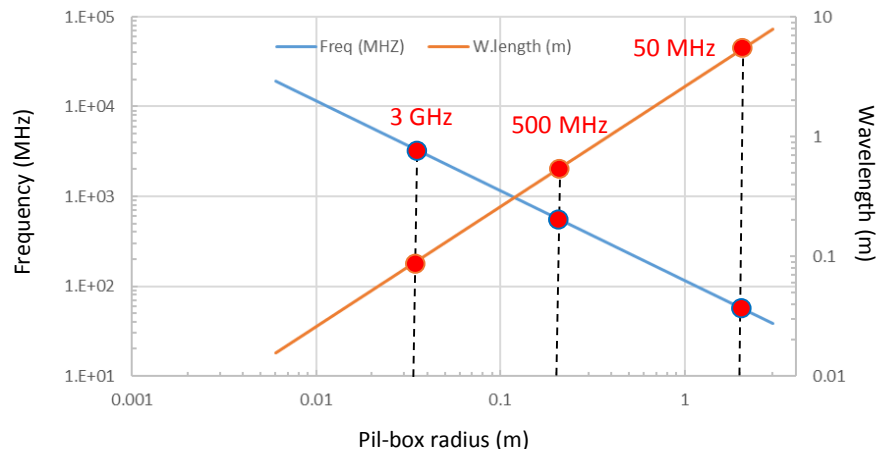
Fundamental mode for accelerating structures  $TM_{010}$   
The Resonance frequency is independent of  $h$

$$f_o = \frac{2.40483 c}{2\pi a}$$



### Standing Wave cavity

Superposition of two counter-propagating waves

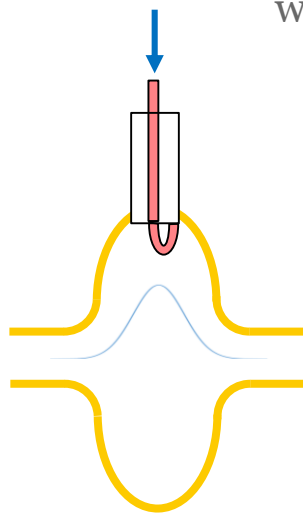


The higher the frequency and the tighter are the mechanical tolerances

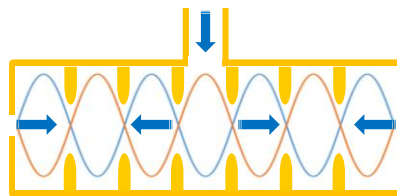


# Some more realistic types of acc. structures

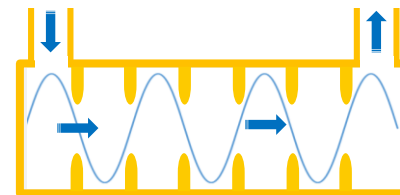
we need apertures for the beam and to power the structure



Standing wave  
Elliptical shape



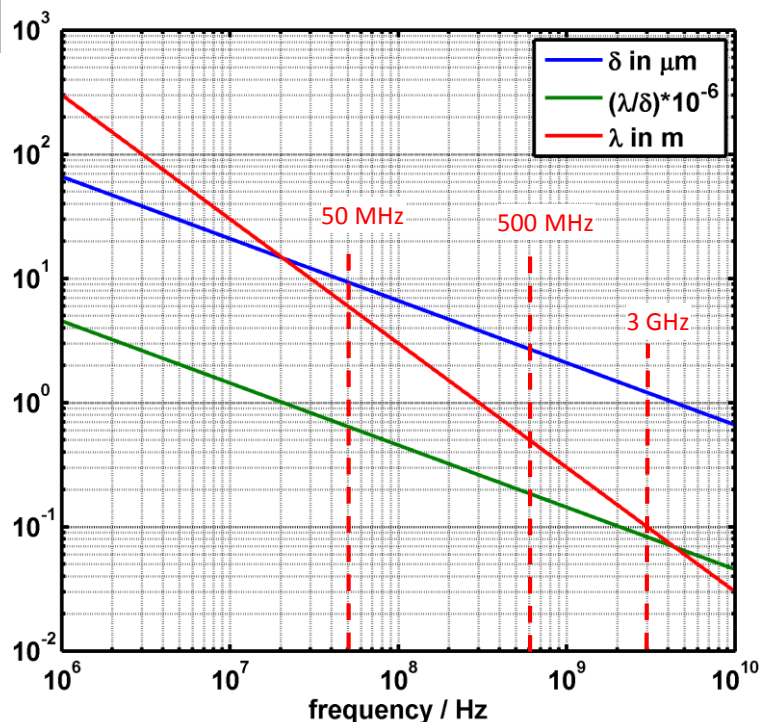
Standing wave  
Multi Cells



Traveling wave  
Multi Cells

**Constraints:** The longitudinal size of the cells and spacing must be adjusted to the transit time of the particle bunches to keep the synchronism with the RF

The magnetic field  $H$  tangential to the surfaces induce a current  $\vec{J}_A = \vec{n} \times \vec{H}$  in the skin depth  $\delta$



$$\delta = \sqrt{\frac{\rho}{\pi f \mu_r \mu_0}}$$

$\rho_{\text{copper}} = 0.017 \Omega \cdot \text{mm}^2/\text{mm}$  resistivity

$\mu_0 = 4\pi \cdot 10^{-7} \text{ A/N}^2$  permeability constant

$\mu_r = 1$  (in Vacuum) relative permeability

$$R_s = \frac{\rho}{\delta} \propto \sqrt{\rho}$$

is the surface resistance (1 m $\Omega$  at 1 GHz)

$$P_{\text{loss}} = \iint_{\text{wall}} R_s |H_t| dA \quad \text{is the total power loss on the cavity wall}$$

$$Q_0 = \frac{\omega_0 W}{P_{\text{loss}}} = \frac{f_0 2\pi W}{P_{\text{loss}}} \quad \text{defines the (unloaded) Quality factor of the cavity}$$

typically between 15000-50000 for copper cavities

$$W = \iiint \frac{\epsilon}{2} |\vec{E}|^2 + \frac{\mu}{2} |\vec{B}|^2 dV \quad \text{is the energy stored in the cavity}$$

Remind  $\omega = 2\pi f$  is called angular frequency

# Some basic parameters you may face discussing with the RF designer

Coupling factor from an external power source  $\beta = \frac{P_{ext}}{P_{loss}}$

$\beta=1$  matched to the wall losses (no Beam)  $\Rightarrow$  ext. source just compensating the losses

$Q_{ext} = \frac{\omega_0 W}{P_{ext}} = \frac{Q_0}{\beta}$  ( $P_{ext}$  can be alternatively interpreted as the losses from the coupler when the RF source is turned off)

With external source the total quality factor becomes  $Q_L = \frac{Q_0}{1+\beta}$

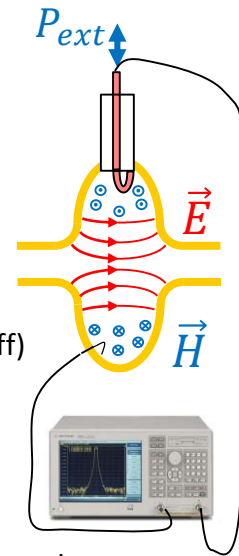
Shunt impedance:  $R = \frac{|V_{acc}|^2}{2P_{loss}}$   $\rightarrow$  Optimized by the RF designer to minimize the power requirements

R «upon» Q:  $\frac{R}{Q} = \frac{|V_{acc}|^2}{2\omega W_0}$

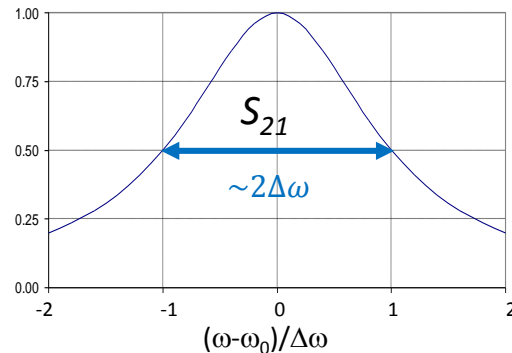
figure of merit of the cavity shape (material independent) as high as possible

Cavity Bandwidth:  $\Delta\omega = \frac{\omega_0}{2Q_L}$

Cavity filling time:  $\tau_L = \frac{1}{\Delta\omega}$



Two ports measurement S21



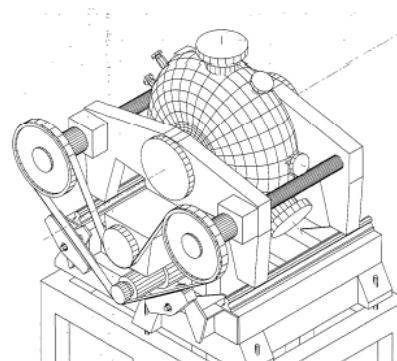
# How to adjust the Resonant frequency

## Permanent adjustment

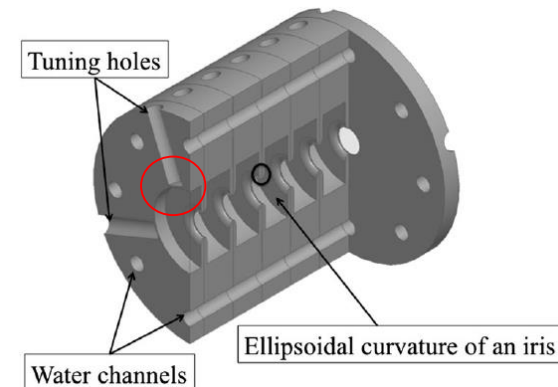
- Inelastic deformation of the cavity wall after manufacture
- Or, very precise manufacturing

## Dynamic adjustment:

- deformation of the cavity wall in elastic regime (fast)
- Motorized plunger (fast)
- Temperature variation (slow)



Example motorized tuning  
SLS 500 MHz cavity



Example dimple tuning opening in a  
C-Band TW structure

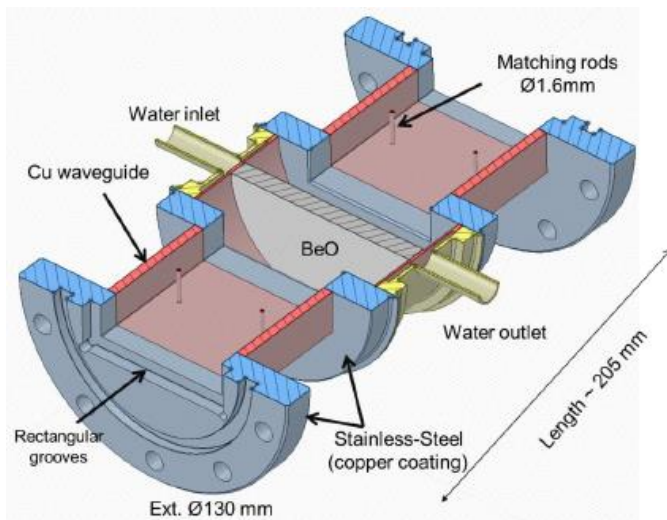
Radius (m)	Res. Freq. (MHz)	$\Delta f$ with + 1°C (kHz)
0.0382	3000	-51
0.23	500	-8.52
2.2	52.2	-0.89

Example Pillbox resonant frequency variation for + 1 °C

## Tendencies for frequency tune methods

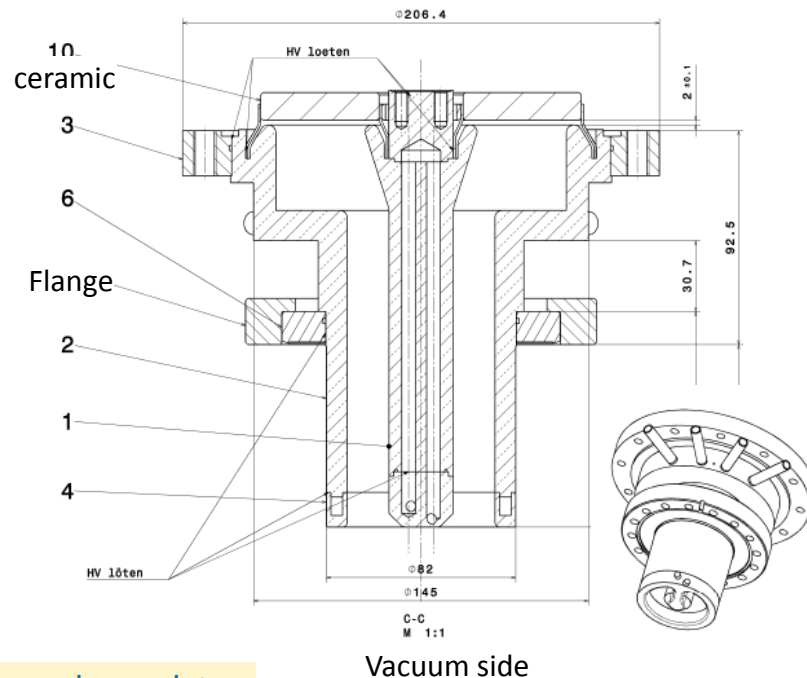
High Freq. : fix tune & temperature  
Low freq. : elastic deformation & plungers

## Wave guide window \*



A metallic thin coating on the vacuum side of the ceramic is commonly used to suppress multipactor and avoid accumulation of charges  $\Rightarrow$  prevents discharges

## 500 MHz Coaxial coupler SLS



For high power applications (large wall losses) a detailed thermal analysis is required to refine both RF and mechanical design in order to:

- avoid hot spots & deformations, (detuning of the structures) and damages
- optimize cooling channels

Multi-physics simulations are therefore required (for example using ANSYS\*)

## Example SwissFEL RF-Gun \*\*

120 MV/m peak RF gradient

14 MW; 100 Hz; 3  $\mu$ s RF pulse

$\beta=2$  for fast filling

3.3 kW average power dissipated

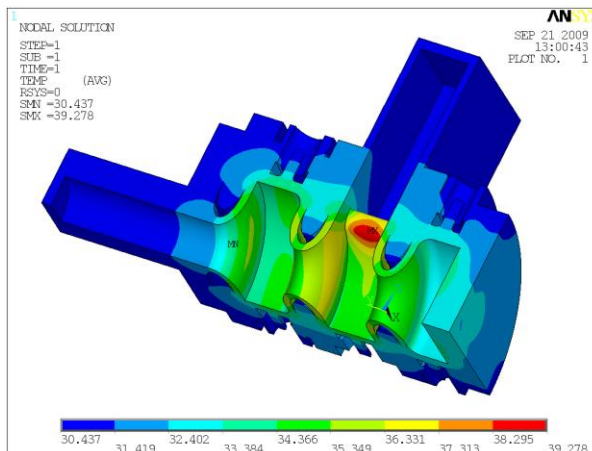
$\alpha_k$ : 7500 W/m<sup>2</sup>K /

Water inlet 30°C

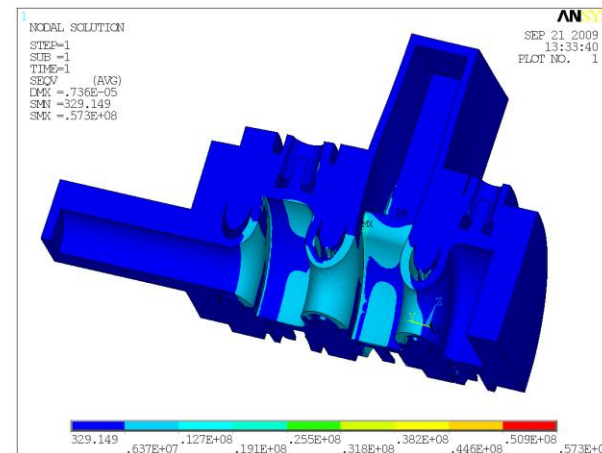
**Always very important!**

Near collaboration between  
RF and mechanical engineer

## Temperature distribution



## Mechanical stresses

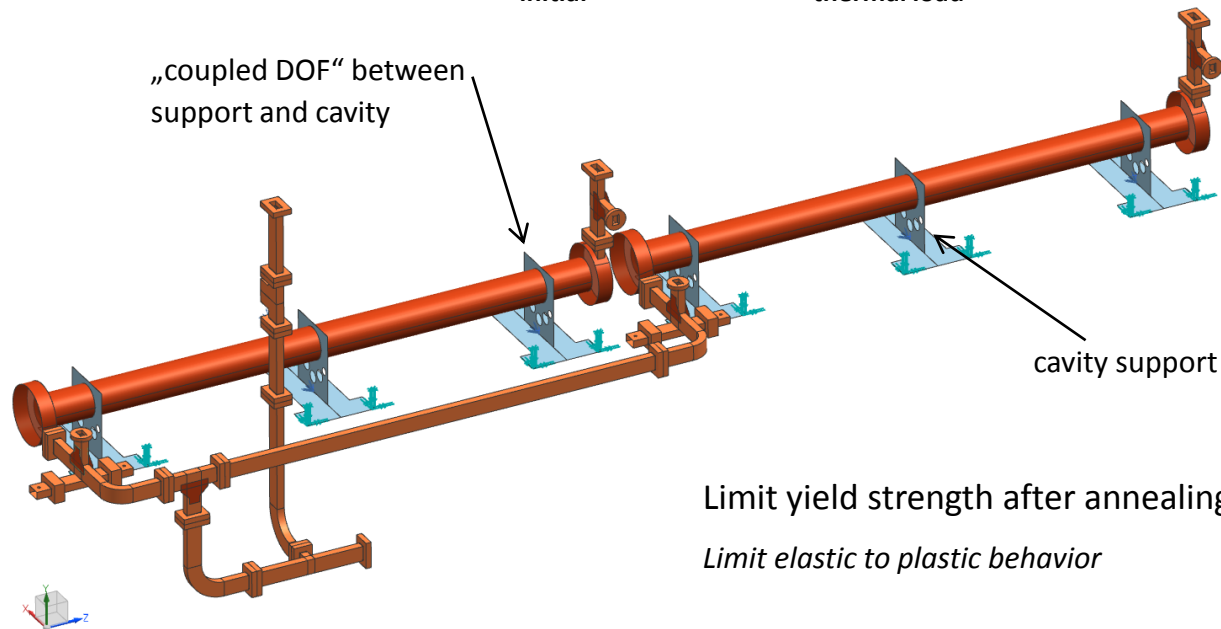


\*<https://www.ansys.com/>



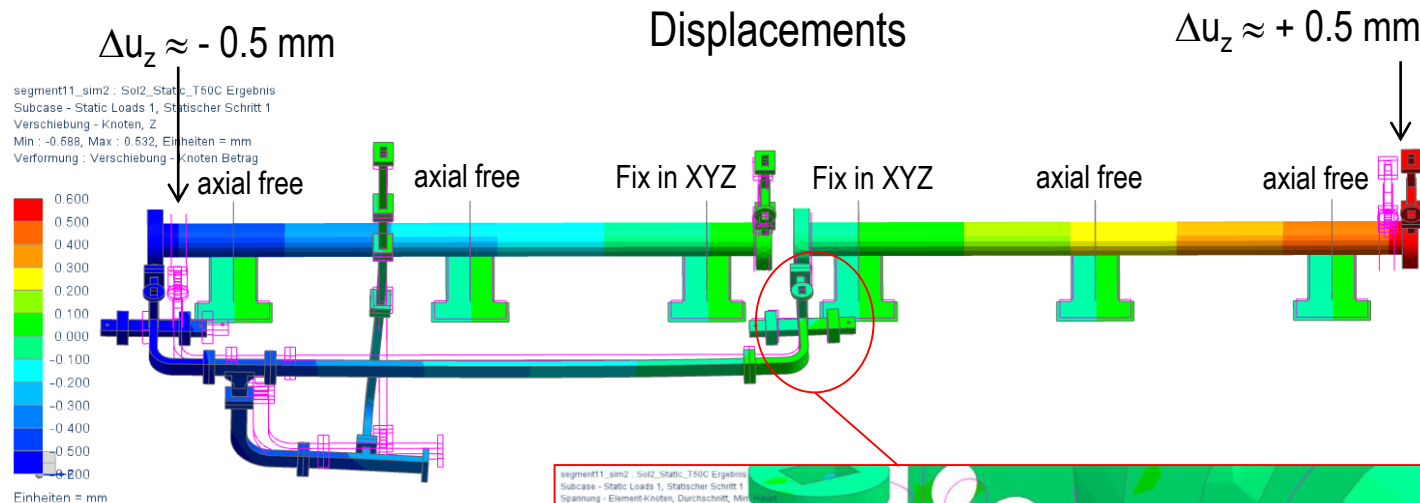
## FEA boundary conditions for stress estimation due to thermal elongations

- All cavity supports translational+rotational fixed in XYZ direction (3 point bearing)
- Each cavity is supported by 1 fixation in XYZ + 2 fixations in XY (with „Coupled DOF“)
- All structures have temperatures of  $T_{\text{initial}} = 25^{\circ}\text{C}$  and  $T_{\text{thermal load}} = 50^{\circ}\text{C}$  (operation  $30^{\circ}\text{C}$ )



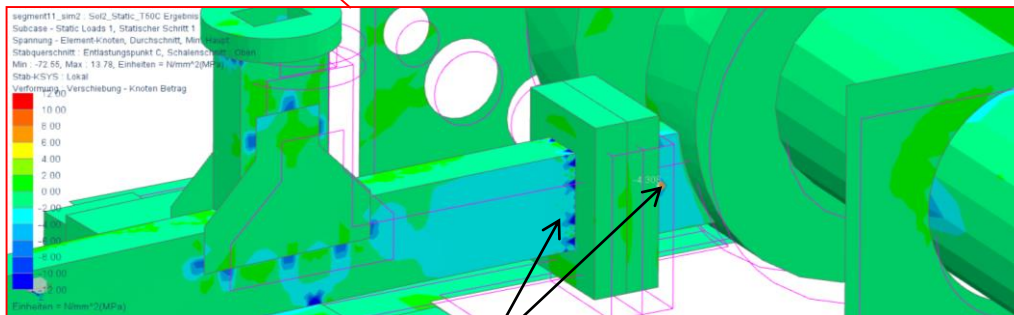
Limit yield strength after annealing  $\sim 40 \text{ MPa}$

*Limit elastic to plastic behavior*



Stress far from limits

Important for the design of the supports

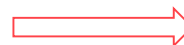


$\sigma_{\text{max, bending}} \approx 4.5 \text{ MPa}$

# Oxygen Free High Conductivity Copper material of choice for RF structures

## PSI Specifications for SwissFEL:

The impurities shall be in accordance with ISO 431 except:



### Reasons

- Relatively easy to machine & with roughness at nm level
- Low Secondary Emission coefficient to reduce multipacting & breakdown risks
- Excellent electrical (and thermal) conductivity  $\Rightarrow$  minimize power dissipation
- Easy to braze/weld
- Good availability and reasonable cost

} Suitable for high RF  
accelerating gradients

### Copper must be 3D forged

- To increase mechanical uniformity, hardness and strength of the material
- Minimize number and size of defects, cracks and empty inclusions that could lead to craters or virtual leaks in vacuum after machining.

Element	% in Cu-OFE
Copper	99.99
Cadmium max.	0.0001
Phosphorus max.	0.0003
Sulphur max.	0.0018
Zinc max.	0.0001
Mercury max.	0.0001
Lead max.	0.001
Selenium max.	0.001
Tellurium max.	0.001
Bismuth max.	0.001
Arsenic Antimony Bismuth Selenium Tellurium Tin Manganese	Total of these seven elements not to exceed 40 ppm

# Resonant cavities: few important information to be kept

The resonant frequency depends on the dimensions of the cavity. Active deformations are used to tune the frequency but unwanted mechanical deformations (effect of vacuum, thermal excursions, stress) have the same effect

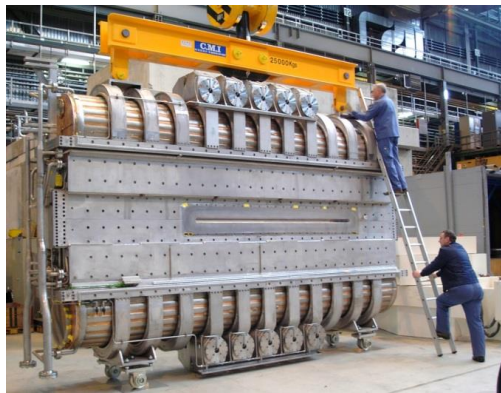
The highest the frequency the most sensitive is the RF structure to manufacturing tolerances or deformations  $\Rightarrow$  to match the design resonant frequency within the allowed tuning range

The power losses can be minimized with a “smart” RF design. Materials are of course important (OFHC copper). Thermal analysis starting from the simulated RF losses helps optimizing the design

The highest the unloaded quality factors  $Q_0$  the lower are the wall losses, and narrow the bandwidths of the structure. The final quality factor  $Q_L$  depends on the coupling factor to the source.

The near collaboration between RF and mechanical engineer in an iterative process is essential to rapidly converge to a feasible and (reasonably) optimized design. Compromises between RF performances and mechanical feasibility can't be avoided.

# PSI RF structures: frequency Zoo



50 MHz Ring Zyklotron



50 MHz Inj. II

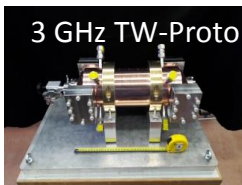
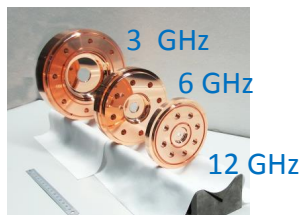


150 MHz buncher



500 MHz Super-buncher

Disks for TW-struct.



3 GHz TW-Proto

50 MHz  $\longleftrightarrow$  12 GHz

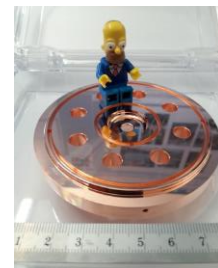
6 GHz TW-SwissFEL  
After brazing at PSI



12 GHz Deflector  
Assembly In SwissFEL

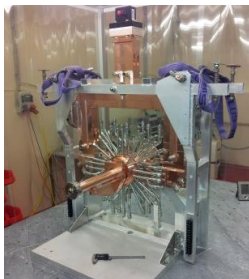


12 GHz Disc



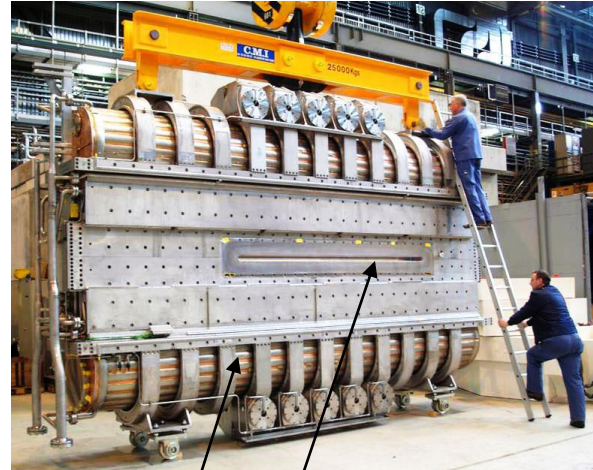
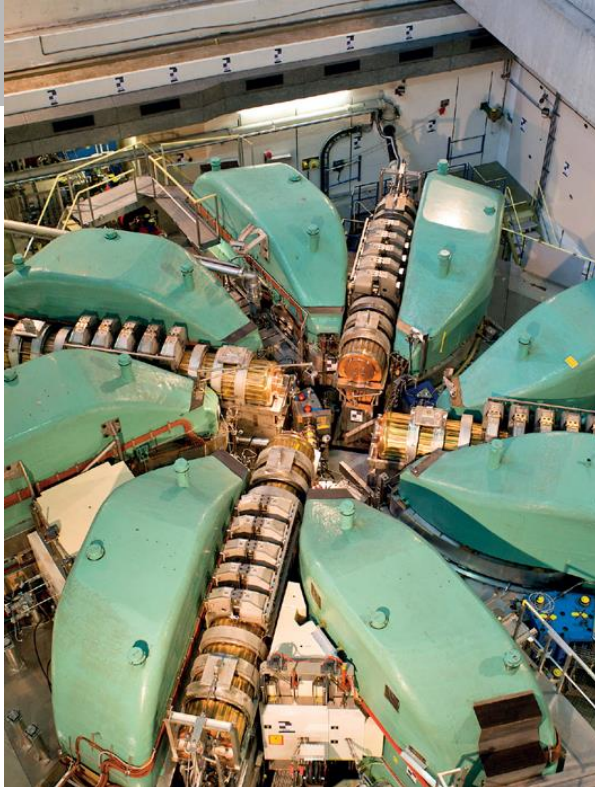
1.5 GHz 2 cell LEG

3 GHz RF-Gun  
SwissFEL





# Examples: High Intensity Proton Accelerator at PSI, 50 MHz RF System



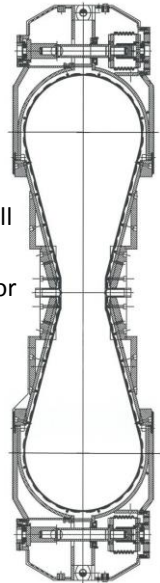
Opening for the beam

External structure for the frequency tuning by (pneumatic) deformation of the cavity



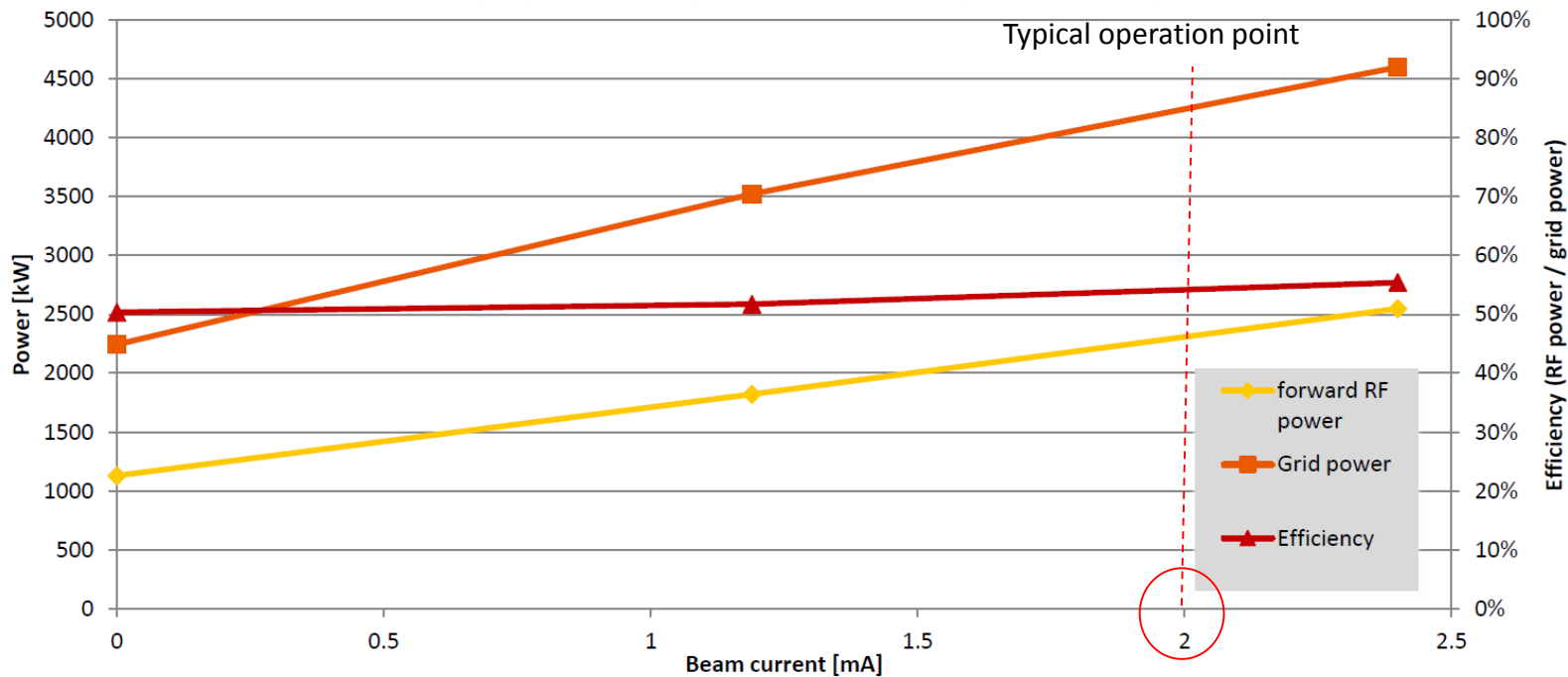
1 MW Tetrode final amplification stage

- Copper to minimize the wall losses
- Shape to reduce multipactor





## HIPA Ring cyclotron power consumption RF system



Proton beam power > 1 MW!  
Energy 590 MeV

# Example: SwissFEL Injector S-band structures

## PSI RF design

- Constant gradient + constant losses
- Dual feed racetrack couplers

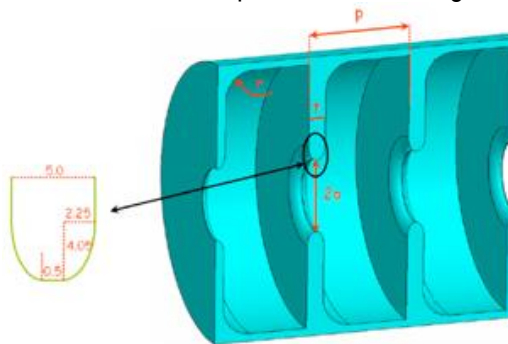
Classical technology with cell to cell dimple tuning after brazing

Manufacturing incl. machining, brazing & tuning by Research Instruments  
2008-09

Parameter	Value		
Operating frequency	2998.8 MHz		
Phase advance per cell	$2\pi/3$		
Total number of cells	122		
Accelerating gradient	20 MV/m		
Maximum pulse repetition frequency	100 Hz		
Operating temperature	30°C		
	$v_g/c$ (%)	$r/Q$ (k $\Omega$ /m)	$Q$
First cell	2.91	3.85	11688
Middle cell	1.87	4.23	11640
Last cell	0.79	4.81	11589

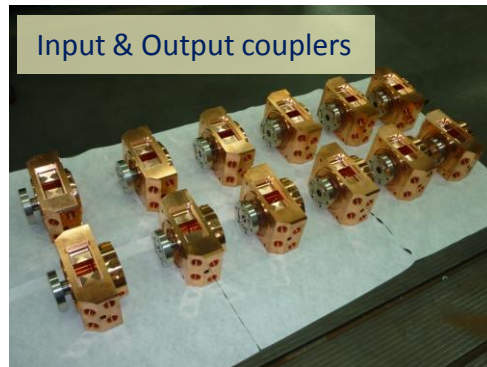


Coupler cell with waveguide

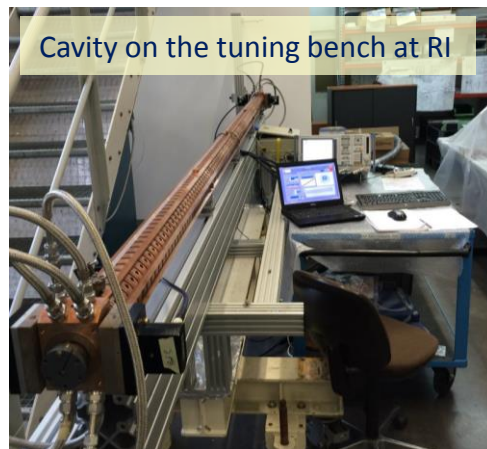


Geometry of 3 regular cells  
(120 regular cells + 2 coupling cells)

Input & Output couplers



Cavity on the tuning bench at RI



# New frontiers with Ultra High Precision machining

- This make sense for structures at high frequencies operating at fixe tune
- The idea is to manufacture on tune => i.e. the exact dimensions of the structures as simulated by the RF engineers
- Prerequisite
  - Very high level of confidence in the RF design simulation tools (HFFS\*, CST\*\*, ...).
  - Relay on UHP machining with tolerances in the  $\mu\text{m}$  range (qualify commercial partner for large series)
  - In house expertise for the mechanical design and production process (need time to be established)
  - In house expertise (and possibly the oven) for the brazing process
- Advantages
  - Structure ready for use direct after brazing.
  - Avoid «long» tuning process with possible contamination of the structure surfaces
  - Very low roughness of the surfaces – typically **Ra <15 nm**



} Good for high gradient applications

\* <https://www.ansys.com/products/electronics/ansys-hfss>

\*\* <https://www.3ds.com/products-services/simulia/products/cst-studio-suite/>

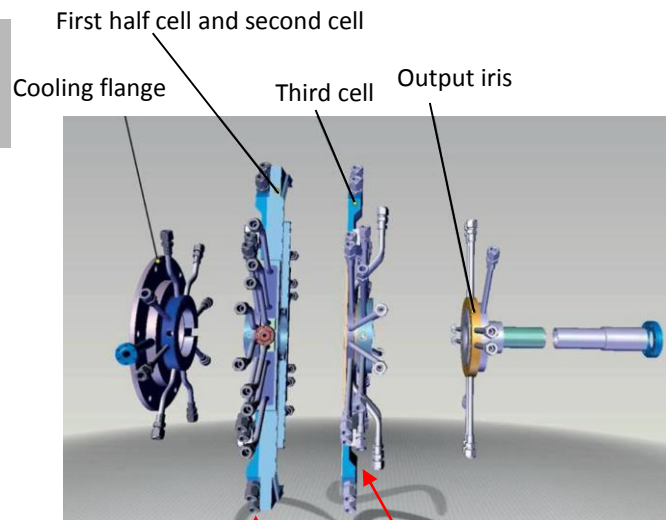
Manufacturing temperature  $\neq$  operating temperature of the structure

The dimensions on the manufacturing drawings must be adapted taking into account:

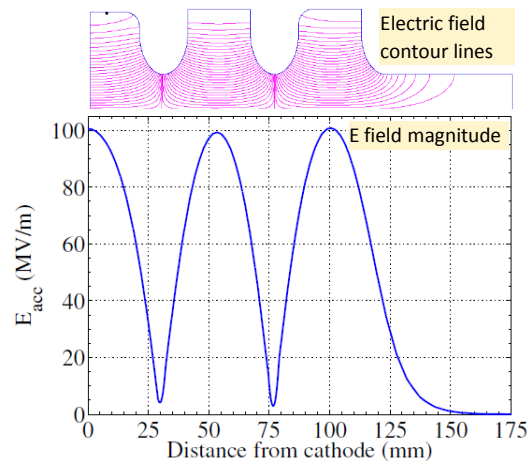
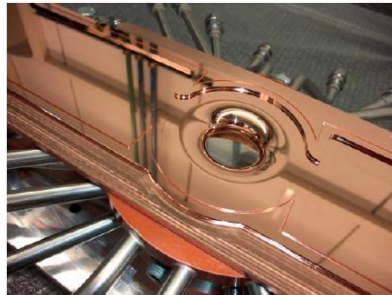
- The temperature of the UHP workshop environment (temperature stabilized)
- The final operating temperature of the cavity

Seems trivial but remember we want to achieve precisions in few  $\mu\text{m}$  range

# UHP example: SwissFEL S-Band RF Gun



Coupling aperture in the second cell

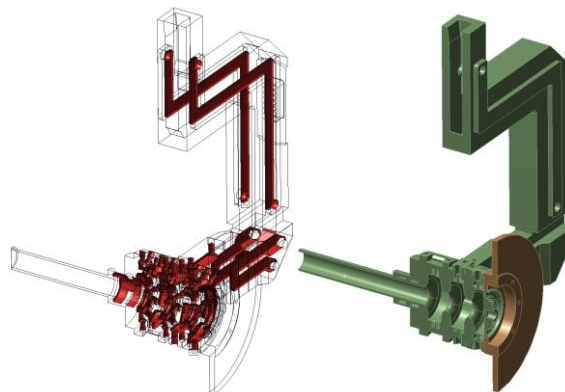


**First structure fabricated with UHP techniques at PSI (cells of cavity body).**

**Fabrication on tune according to RF simulations**

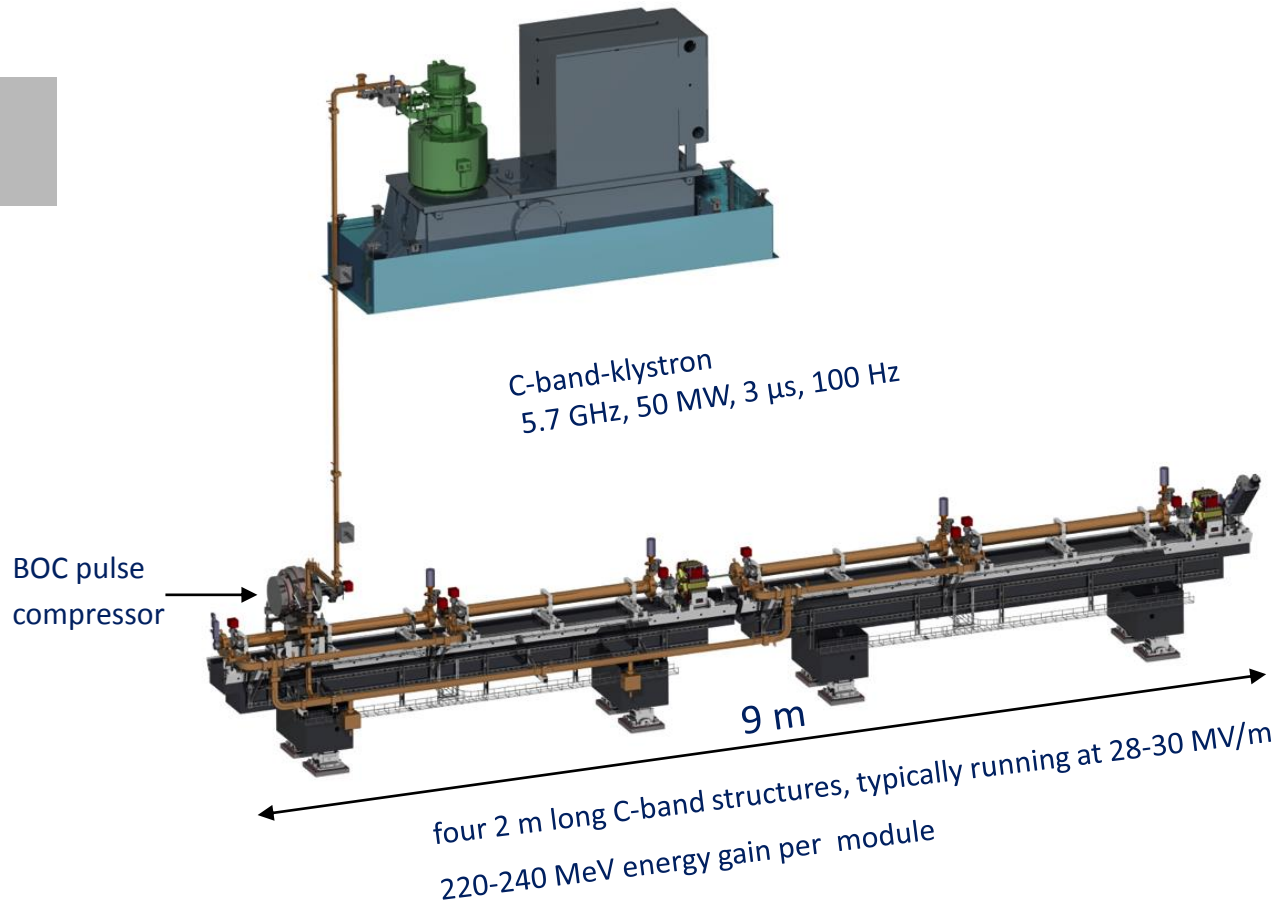
**No Correction of tuning and field balance required after final brazing.**

**Few  $\mu\text{m}$  tolerances (outer diameter cells)**



Cooling was dimensioned for 4 kW

# UHP example: C-band linac modules



Main LINAC	#
LINAC module	26
Modulator	26
Klystron	26
Pulse compressor	26
Accelerating structure	104
Waveguide splitter	78
Waveguide load	104

## UHP

- BOC (less stringent requirements)
- Accelerating structures



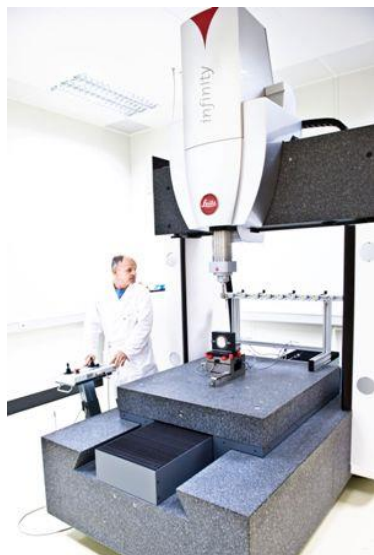
# Some production infrastructure



UP-Machine HEMBRUG Slantbed-MIKROTURN-100-CNC  
Was used to establish the manufacture procedure at PSI  
Later delivered to the industrial partner for mass production



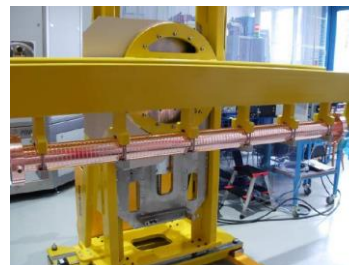
Brazing furnace @ PSI



Metrology: Leitz Infinity: accuracy 0.3  $\mu\text{m}$ .



7 sequential cleaning baths with  
automatized cup handling



Handling tools



Automatized stacking with robot



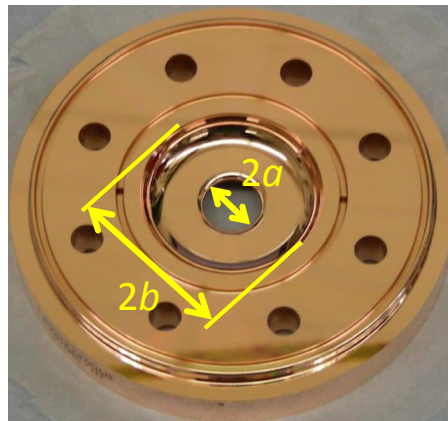
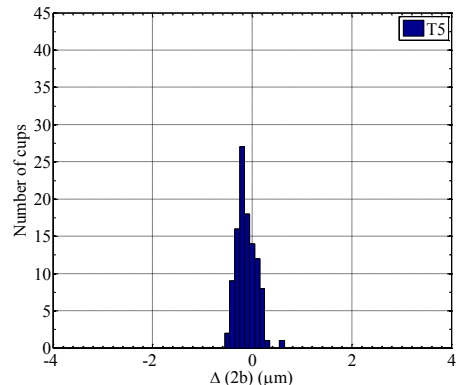
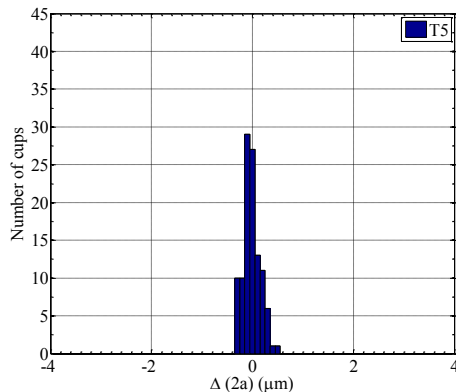
# UHP example: SwissFEL C-Band structures



Structure ready to be brazed

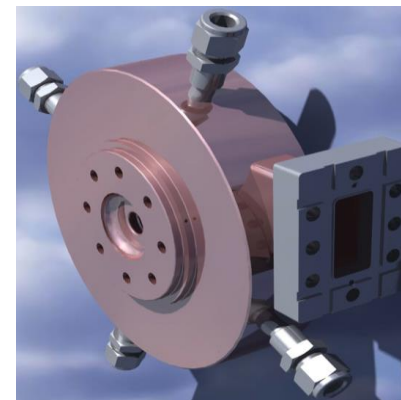
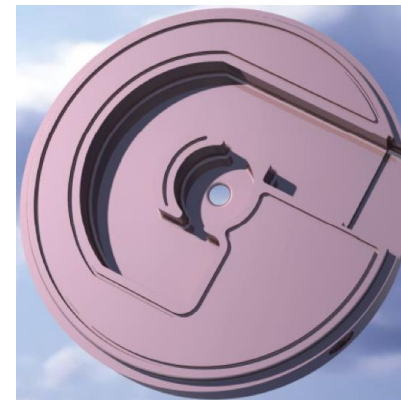
- Structures are machined “on tune”, no provisions for dimple tuning!
- Cup manufacturing with micron precision (VDL ETG Switzerland)
- Coupler manufacturing at VDL ETG
- Stacked by robot at PSI
- Vacuum-brazed at PSI
- Production rate: 1-2 / week
- Production finished August 2016
- **High power results for first structure:**
  - Conditioned to 52 MV / m (limited by Power availability)
  - Break-down rate at 52 MV / m  
 $\approx 2 \times 10^{-6}$
  - At nominal 28MV/m,  
break-down rate negligible (well below the specified  
threshold of  $10^{-8}$ )

R. Zennaro et al., “Measurement and High Power Test of the First C-Band Accelerating Structure for SwissFEL”, Proceedings of LINAC2014, Geneva, Switzerland



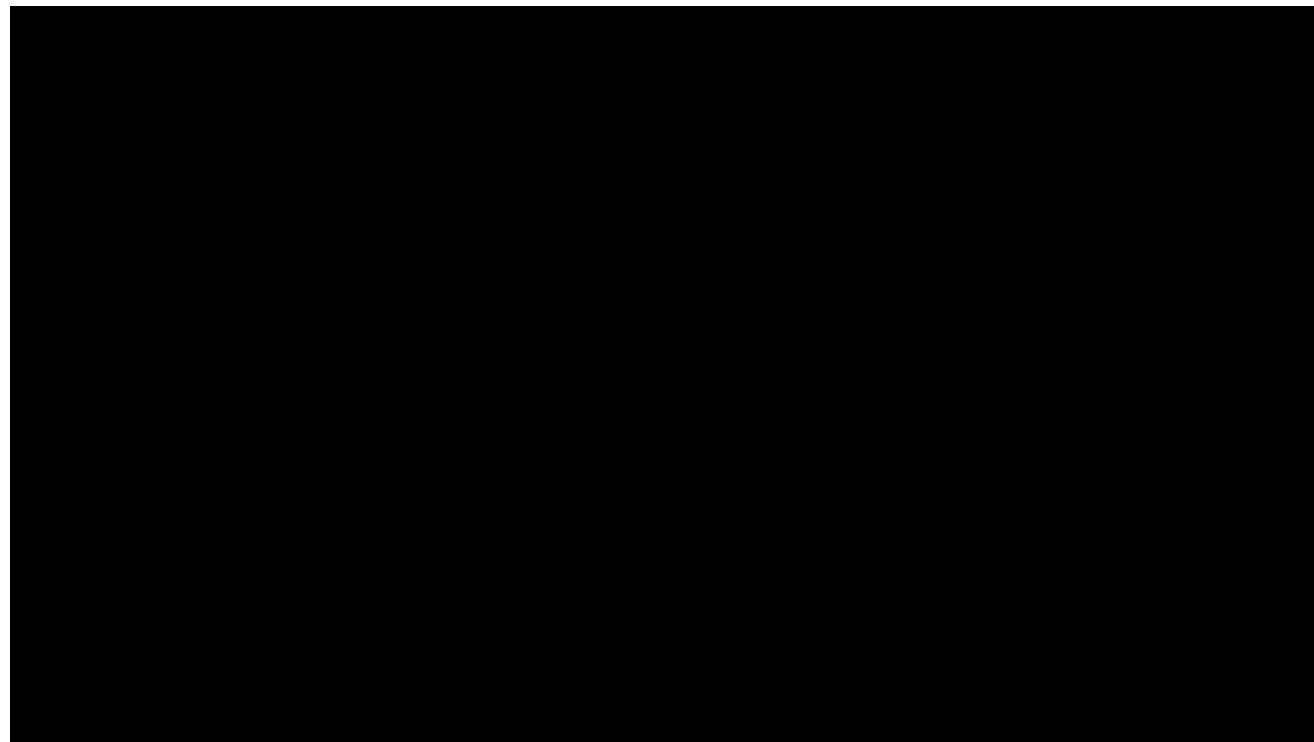
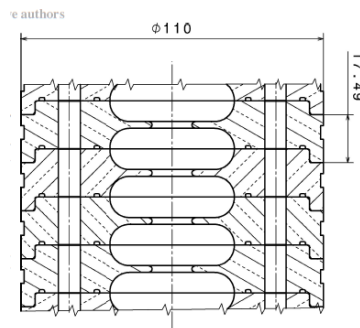
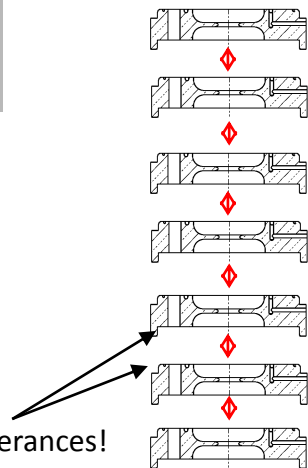
Regular cell

J coupler cell

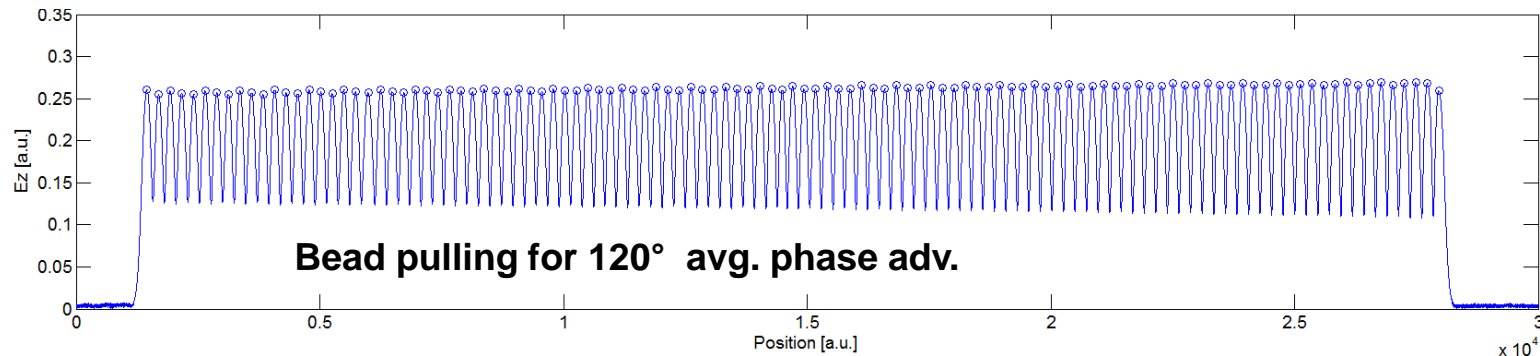


Typical examples of metrology on a structure:  
top histogram iris diameter, bottom histogram iris cell diameter

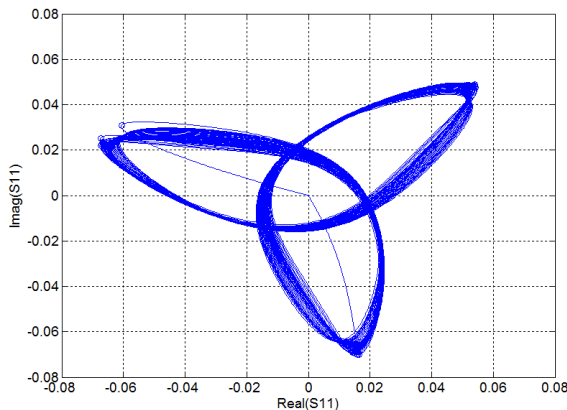
# UHP & tricks for cup stacking



VSWR = 1.06

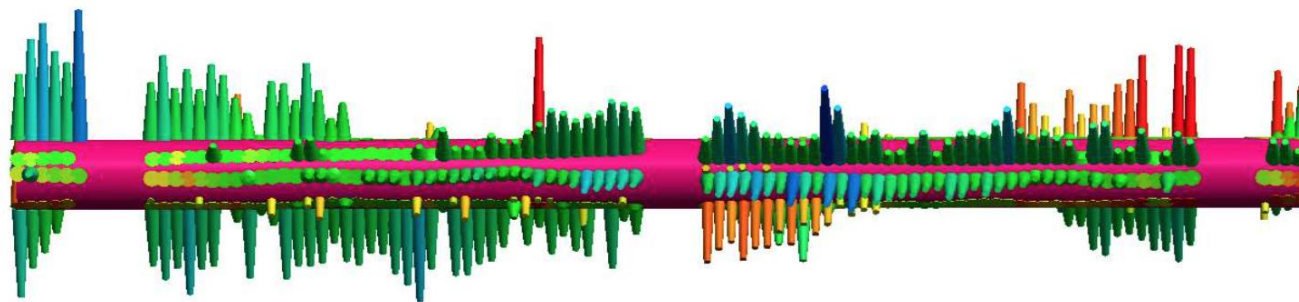
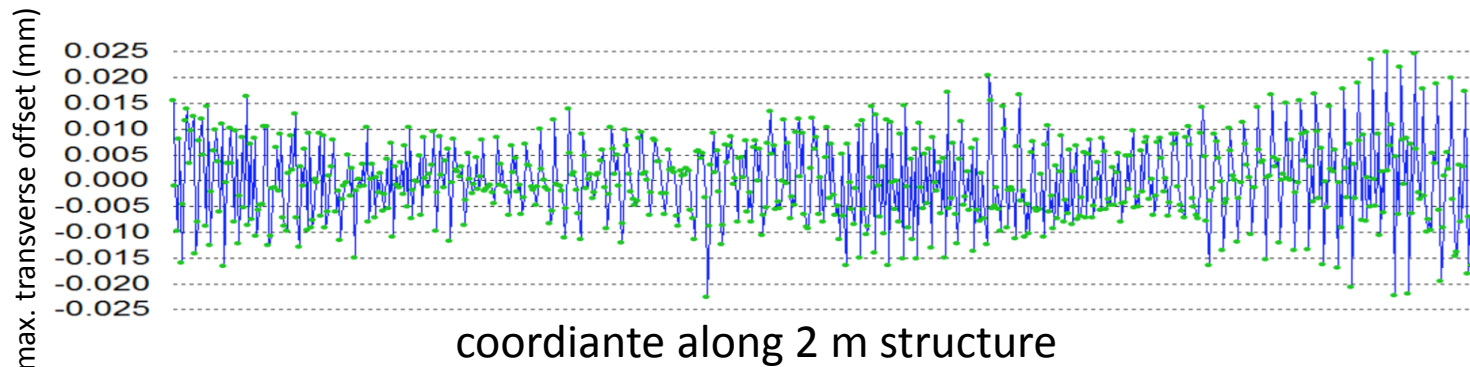


RMS phase error typically < 1 deg



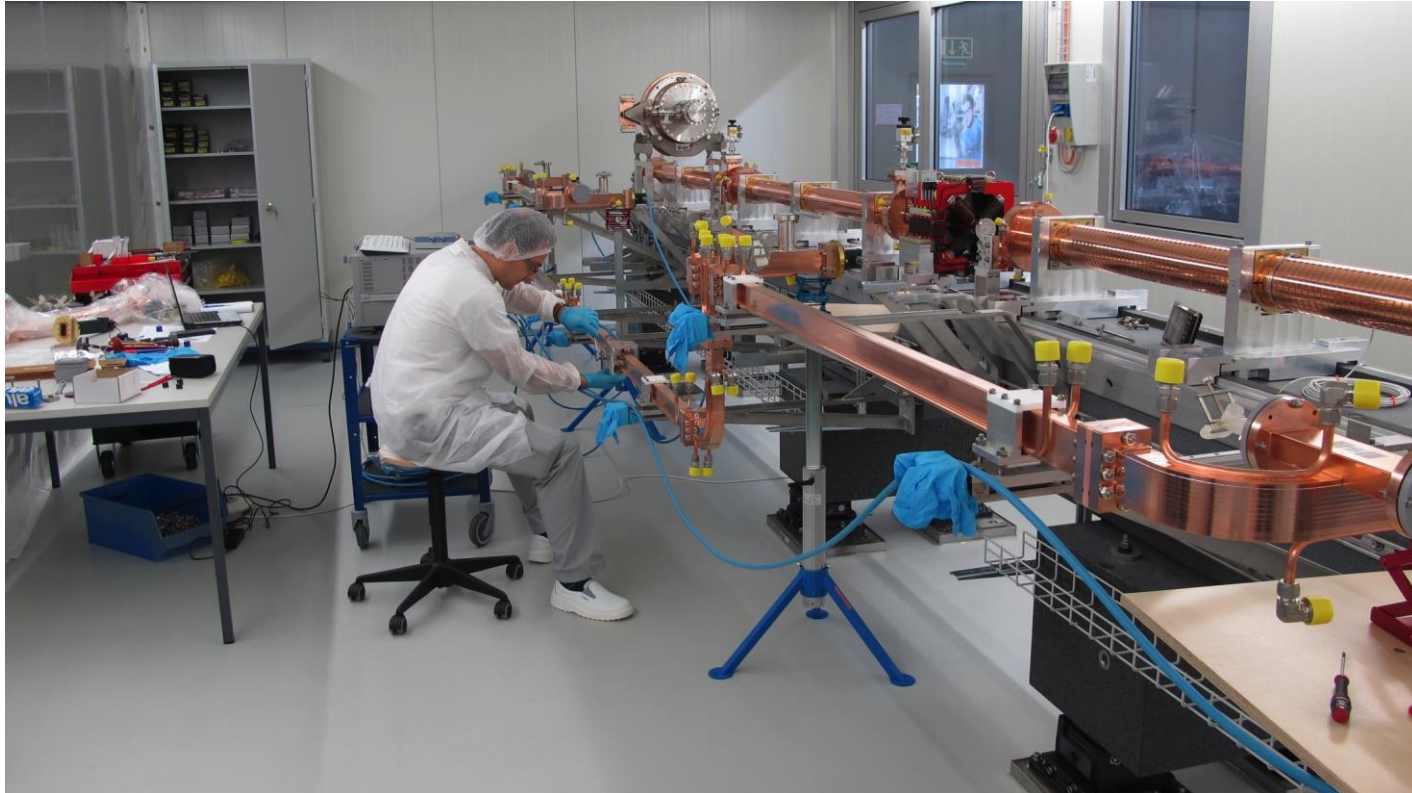
I shall be noted that during the brazing process the structure expands longitudinally ~20 mm  
After cooling down the tolerances are preserved and the cavity is on tune!

# C-band structures: typical straightness



→ Max. deviation from straight trajectory typically  $< 20 \mu\text{m}$

# C-Band module: Preassembly and tuning of the waveguide train





## RF design:

- ✓ intrinsic high  $Q_0 > 200000$
- ✓  $\beta=10$

Adapted from the original design for S-Band of  
I. Syratchev (CERN).

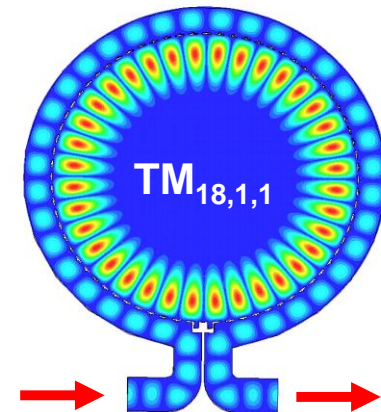
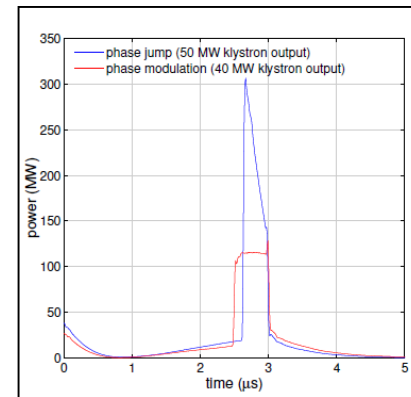
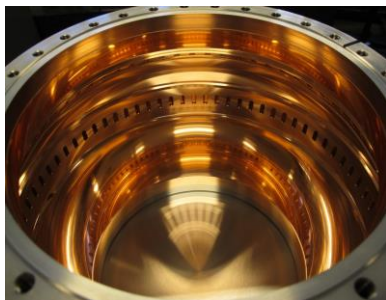
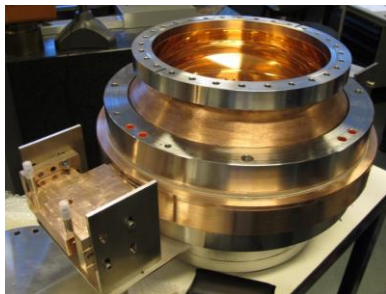
## Mechanical design:

Simple and robust design:

- ✓ Inner body from a single piece
- ✓ Two brazing steps
- ✓ Machined on tune

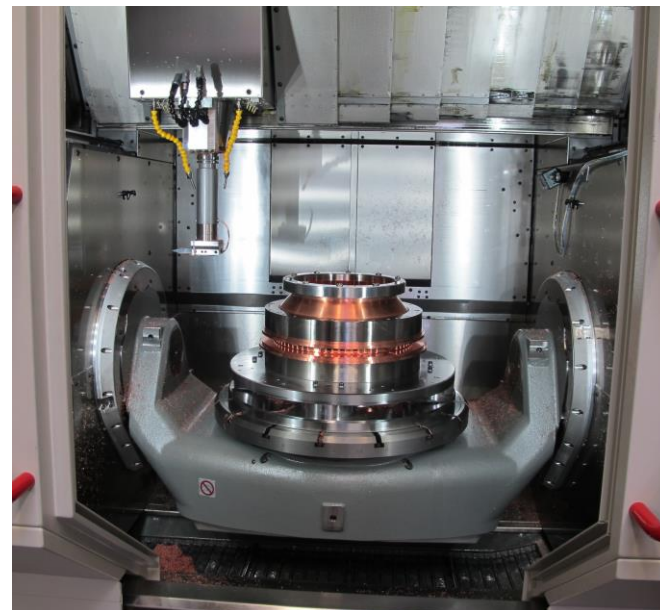
## Production:

- ✓ 100% in house



- R. Zennaro et al., "C-band RF pulse compressor for the SwissFEL", Proc. IPAC 2013, Shanghai
- U. Ellenberger et al., "The SwissFEL C-Band RF Pulse Compressor: Manufacturing and Proof of Precision by RF Measurements", FEL 2014, Basel
- A. Citterio et al., "C-band Load Development for the High Power Test of the SwissFEL RF Pulse Compressor", LINAC 2014, Geneva
- I. V. Syratchev, "RF pulse compressor systems for CTF3", Proc. 5-th MDK Workshop, Geneva, June 2001.





Hermle C42 U: 5 axis machine for BOC production at PSI

The chosen RF mode (size of the cavity) allow for more relaxed tolerances  $\pm 10\mu\text{m}$

Mechanical stress was an issue => very thin wall in the coupling ring 1.8 mm

# Impression in the SwissFEL tunnel

350 m of Linac



A very near exchange between RF and mechanical engineers is essential for an efficient development work  $\Rightarrow$  iterative process.

Very important to reach a common understanding of both mechanical and RF constraints to avoid losing time with nearly unfeasible designs.

A core group with a mechanical engineer and experienced draft men must be permanently integrated within the RF team to:

- build and maintain the necessary engineering know-how in the field of RF (learn from the past experience)
- ensure an efficient communication with the workshop and external suppliers

The progress with the RF simulation tools and UHP machining allows extreme precise design and fabrication on tune. Prototyping phase to validate the design may be avoided or strongly reduced.



## My thanks go to

- you all for listening
- the RF section at PSI
- the PSI Workshop
- The very fruitful exchanges with numerous colleagues from other institutions



- (1) **CAS: RF for Accelerators, 08 - 17 June 2010, Ebeltoft, Denmark**  
<https://cas.web.cern.ch/schools/ebeltoft-2010>
- (2) **CAS: RF Engineering, 01 - 10 May 2000, Seeheim, Germany**  
<https://cas.web.cern.ch/schools/seeheim-2000>
- (3) **CAS: RF Engineering for Particle Accelerators, 01 - 10 September 1991, Oxford, UK**  
<https://cas.web.cern.ch/schools/oxford-1991>